











SN75468, SN75469

SLRS023E - DECEMBER 1976 - REVISED JANUARY 2015

SN7546x Darlington Transistor Arrays

1 Features

- 500-mA Rated Collector Current (Single Output)
- High-Voltage Output 100 V
- · Output Clamp Diodes
- Inputs Compatible With Various Types of Logic
- Relay Driver Applications
- Higher-Voltage Versions of ULN2003A and ULN2004A, for Commercial Temperature range

2 Applications

- Relay Drivers
- Hammer Drivers
- Lamp Drivers
- Display Drivers (LED and Gas Discharge)
- Line Drivers
- Logic Buffers

3 Description

The SN75468 and SN75469 are high-voltage, high-current Darlington transistor arrays. Each consists of seven NPN Darlington pairs that feature high-voltage outputs with common-cathode clamp diodes for switching inductive loads. The collector-current rating of each Darlington pair is 500 mA. The Darlington pairs may be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers.

The SN75468 has a 2700- Ω series base resistor for each Darlington pair for operation directly with TTL or 5-V CMOS. The SN75469 has a 10.5-k Ω series base resistor to allow its operation directly with CMOS or PMOS that use supply voltages of 6 to 15 V. The required input current is below that of the SN75468.

Device Information⁽¹⁾

PART NUMBER	PACKAGE (PIN)	BODY SIZE (NOM)		
	D (16)	9.90 mm × 3.91 mm		
SN7546x	N (16)	19.30 mm × 6.35 mm		
	NS (16)	10.30 mm × 5.30 mm		

(1) For all available packages, see the orderable addendum at the end of the datasheet.

4 Simplified Schematic

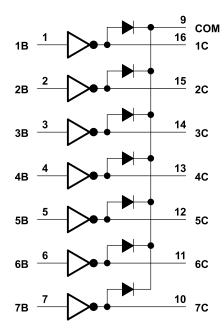




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5 Revision History

Changes from Revision D (November 2004) to Revision E

Page

Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table,
Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation
section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and
Mechanical, Packaging, and Orderable Information section.

Deleted Ordering Information table.

Product Folder Links: SN75468 SN75469

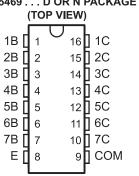
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6 Pin Configuration and Functions

SN75468 ... D, N, OR NS PACKAGE SN75469 ... D OR N PACKAGE



Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.	ITPE	DESCRIPTION
<1:7>B	1 - 7	I	Channel 1 through 7 darlington base input
<1:7>C	16 - 10	0	Channel 1 through 7 darlington collector output
E	7	_	Common Emmitter shared by all channels (typically tied to ground)
COM	8	I/O	Common cathode node for flyback diodes (required for inductive loads)

Product Folder Links: SN75468 SN75469

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7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CE}	Collector-emitter voltage		100	V
VI	Input voltage ⁽²⁾		30	V
	Peak collector current		500	mA
I _{OK}	Output clamp current		500	mA
	Total emitter-terminal current		-2.5	Α
T_J	Operating virtual junction temperature		150	°C
T _{stg}	Storage temperature range	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	±2000	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	±500	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
V _I	0	5	V
V _{CC}	0	100	V
T _J Junction Temperature	-40	125	°C

7.4 Thermal Information

		SN7546x	
	THERMAL METRIC ⁽¹⁾	D	UNIT
		16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	73	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	40.3	
$R_{\theta JB}$	Junction-to-board thermal resistance	38.9	9 0 // //
ΨЈТ	Junction-to-top characterization parameter	10.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	38.7	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

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⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.5 Electrical Characteristics

 $T_A = 25$ °C (unless otherwise noted)

	DADAMETED	TEST CO.	NDITIONS(1)	S	N75468		s	N75469		LINUT	
PARAMETER		IESI CO	TEST CONDITIONS ⁽¹⁾		TYP	MAX	MIN	TYP	MAX	UNIT	
			I _C = 125 mA								
			I _C = 200 mA			2.4					
.,	On state is set to the set	V 0.V	I _C = 250 mA			2.7					
$V_{I(on)}$	On-state input voltage	$V_{CE} = 2 V$	I _C = 275 mA							V	
			I _C = 300 mA			3					
			I _C = 350 mA								
V _{CE(sat)} Collector-emitter satu		I _I = 250 μA, IC = 10	I _I = 250 μA, IC = 100 mA		0.9	1.1		0.9	1.1	+	
	Collector-emitter saturation voltage	I _I = 350 μA, IC = 100 mA			1	1.3		1	1.3		
		I _I = 500 μA, IC = 10		1.2	1.6		1.2	1.6			
V _F	Clamp-diode forward voltage	I _F = 350 mA			1.7	2		1.7	2	V	
		V _{CE} = 100 V, I _I = 0				50			50		
I _{CEX}	collector cutoff current	V _{CE} = 100 V,	I _I = 0			100			100	μΑ	
		TA = 70°C	V _I = 1 V						500		
I _{I(off)}	Off-state input current	V _{CE} = 50 V, I _C = 50	00 μA, T _A = 70°C	50	65		50	65		μΑ	
		V _I = 3.85 V			0.93	1.35					
I	Input current	V _I = 5 V						0.35	0.5	mA	
		V _I = 12 V						1	1.45		
	Claren diada variarea aureant	V _R = 100 V				50			50)	
I _R	Clamp-diode reverse current	V _R = 100 V, T _A = 70°C				100			10	μA	
Ci	Input Capacitance	V _I = 0, f = 1 MHz			15	25		15	25	pF	

⁽¹⁾ All electrical characteristics are measured with 0.1- μF capacitors connected at REF, CT, and V_{CC} to GND.

7.6 Switching Characteristics

 $T_A = 25$ °C free-air temperature

PARAMETER		TEST CONDITIONS ⁽¹⁾	MIN	TYP	MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output	$V_S = 20 \text{ V}, R_1 = 163 \Omega, C_1 = 15 \text{ pF},$		0.25	1	μs
t _{PHL}	Propagation delay time, high-to-low-level output	See Figure 14		0.25	1	μs
V _{OH}	High-level output voltage after switching	$V_S = 50 \text{ V}, I_O = 300 \text{ mA}, \text{ See}$ Figure 14	V _S – 20			mV

(1) All switching characteristics are measured with 0.1- μ F capacitors connected at REF and V_{CC} to GND.

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7.7 Typical Characteristics

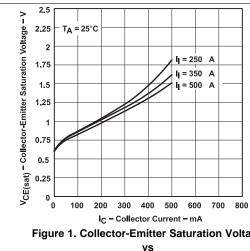


Figure 1. Collector-Emitter Saturation Voltage **Collector Current (One Darlington)**

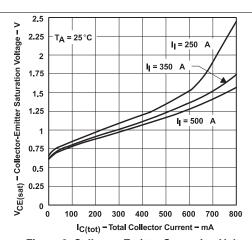


Figure 2. Collector-Emitter Saturation Voltage **Total Collector Current (Two Darlingtons in Parallel)**

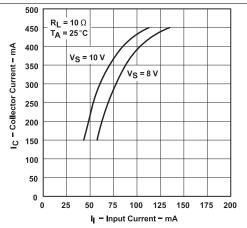


Figure 3. Output Current vs Input Current

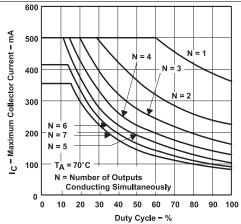


Figure 4. D Package Maximum Collector Current **Duty Cycle**

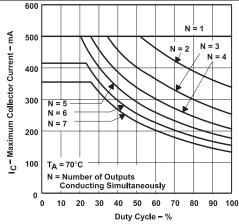


Figure 5. N Package Maximum Collector Current **Duty Cycle**

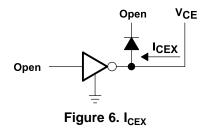
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8 Parameter Measurement Information



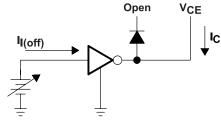


Figure 8. I_{I(off)}

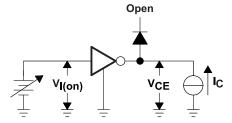


Figure 10. V_{I(on)}

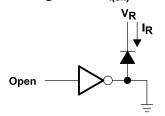


Figure 12. I_R

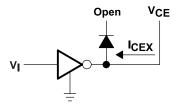


Figure 7. I_{CES}

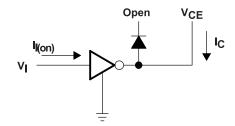


Figure 9. I_I

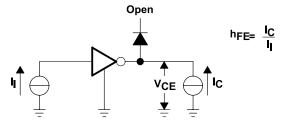


Figure 11. h_{FE}, V_{CE(sat)}

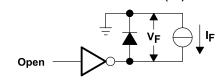
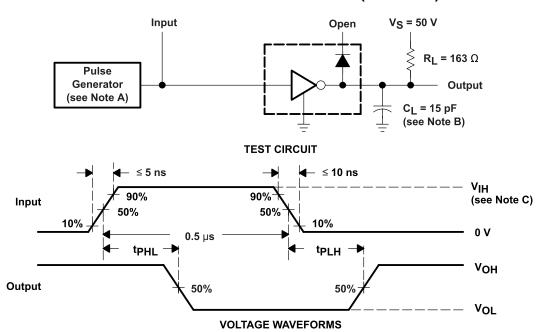


Figure 13. V_F

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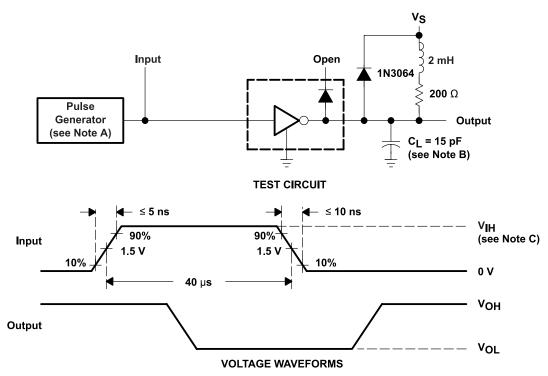


Parameter Measurement Information (continued)



- A. The pulse generator has the following characteristics: PRR = 12.5 kHz, Z_0 = 50 Ω .
- B. CL includes probe and jig capacitance.
- C. For testing the '468, $V_{IH} = 3 \text{ V}$; for the '469, $V_{IH} = 8 \text{ V}$.

Figure 14. Test Circuit and Voltage Waveforms



- A. The pulse generator has the following characteristics: PRR = 12.5 kHz, Z_0 = 50 Ω .
- B. CL includes probe and jig capacitance.
- C. For testing the '468, V_{IH} = 3 V; for the '469, V_{IH} = 8 V.

Figure 15. Latch-Up Test Circuit and Voltage Waveforms

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Detailed Description

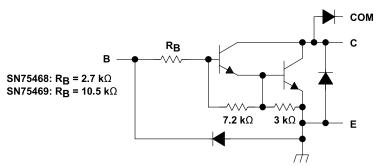
9.1 Overview

This standard device has proven ubiquity and versatility across a wide range of applications. This is due to its integration of 7 Darlington transistors that are capable of sinking up to 500 mA and wide GPIO range capability.

The SN75468 comprises seven high voltage, high current NPN Darlington transistor pairs. All units feature a common emitter and open collector outputs. To maximize their effectiveness, these units contain suppression diodes for inductive loads. The SN75468 has a series base resistor to each Darlington pair, thus allowing operation directly with TTL or CMOS operating at supply voltages of 5.0 V or 3.3 V. The SN75468 offers solutions to a great many interface needs, including solenoids, relays, lamps, small motors, and LEDs. Applications requiring sink currents beyond the capability of a single output may be accommodated by paralleling the outputs.

This device can operate over a wide temperature range (-40°C to 105°C).

9.2 Functional Block Diagram



All resistor values shown are nominal.

9.3 Feature Description

Each channel of SN75468 consists of Darlington connected NPN transistors. This connection creates the effect of a single transistor with a very high current gain (β2). This can be as high as 10,000 A/A at certain currents. The very high β allows for high output current drive with a very low input current, essentially equating to operation with low GPIO voltages.

The GPIO voltage is converted to base current via the 2.7 k Ω resistor connected between the input and base of the pre-driver Darlington NPN. The 7.2 k Ω & 3.0 k Ω resistors connected between the base and emitter of each respective NPN act as pull-downs and suppress the amount of leakage that may occur from the input.

The diodes connected between the output and COM pin is used to suppress the kick-back voltage from an inductive load that is excited when the NPN drivers are turned off (stop sinking) and the stored energy in the coils causes a reverse current to flow into the coil supply via the kick-back diode.

In normal operation the diodes on base and collector pins to emitter will be reversed biased. If these diode are forward biased, internal parasitic NPN transistors will draw (a nearly equal) current from other (nearby) device pins.

9.4 Device Functional Modes

9.4.1 Inductive Load Drive

When the COM pin is tied to the coil supply voltage, SN75468 is able to drive inductive loads and supress the kick-back voltage via the internal free wheeling diodes.

9.4.2 Resistive Load Drive

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When driving a resistive load, a pull-up resistor is needed in order for SN75468 to sink current and for there to be a logic high level. The COM pin can be left floating for these applications.

Product Folder Links: SN75468 SN75469



10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

SN75468 will typically be used to drive a high voltage and/or current peripheral from an MCU or logic device that cannot tolerate these conditions. The following design is a common application of SN75468, driving inductive loads. This includes motors, solenoids & relays. Each load type can be modeled by what's seen in Figure 16.

10.2 Typical Application

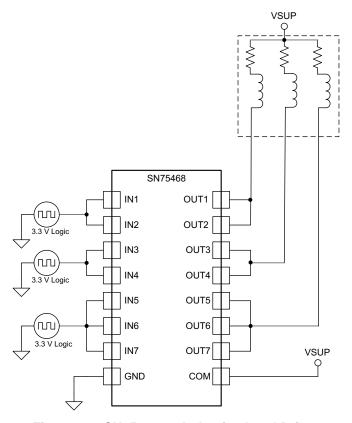


Figure 16. SN75468 as Inductive Load Driver

10.2.1 Design Requirements

For this design example, use the parameters listed in Table 1 as the input parameters.

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
GPIO Voltage	3.3 V or 5.0 V
Coil Supply Voltage	12 V to 100 V
Number of Channels	7
Output Current (R _{COIL})	20 mA to 300 mA per channel
Duty Cycle	100%

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(2)

(3)



10.2.2 Detailed Design Procedure

When using SN75468 in a coil driving application, determine the following:

- · Input voltage range
- · Temperature range
- · Output and drive current
- Power dissipation

10.2.2.1 Drive Current

The coil current is determined by the coil voltage (VSUP), coil resistance & output low voltage (V_{OL} or $V_{CE(SAT)}$). $I_{COIL} = (V_{SUP} - V_{CE(SAT)}) / R_{COIL}$ (1)

10.2.2.2 Output Low Voltage

The output low voltage (V_{OL}) is the same thing as $V_{CE(SAT)}$ and can be determined by the *Electrical Characteristics* table, Figure 1, or Figure 2.

10.2.2.3 Power Dissipation & Temperature

The number of coils driven is dependent on the coil current and on-chip power dissipation. The number of coils driven can be determined by Figure 4 or Figure 5.

For a more accurate determination of number of coils possible, use the below equation to calculate SN75468 onchip power dissipation P_D :

$$P_{D} = \sum_{i=1}^{N} V_{OLi} \times I_{Li}$$

Where

N is the number of channels active together.

$$V_{OLi}$$
 is the OUT_i pin voltage for the load current I_{Li} . This is the same as $V_{CE(SAT)}$

In order to guarantee reliability of SN75468 and the system the on-chip power dissipation must be lower that or equal to the maximum allowable power dissipation ($PD_{(MAX)}$) dictated by below equation Equation 3.

$$PD_{(MAX)} = \begin{pmatrix} T_{J(MAX)} - T_{A} \end{pmatrix} \theta_{JA}$$

Where:

T_{J(MAX)} is the target maximum junction temperature.

T_A is the operating ambient temperature.

 θ_{JA} is the package junction to ambient thermal resistance.

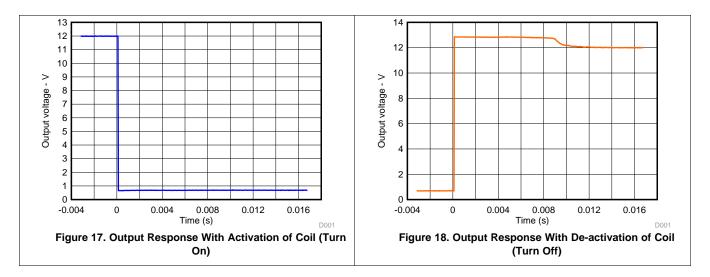
It is recommended to limit SN75468 IC's die junction temperature to less than 125°C. The IC junction temperature is directly proportional to the on-chip power dissipation.

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10.2.3 Application Curves

The following curves were generated with SN75468 driving an OMRON G5NB relay – V_{in} = 5.0V; V_{sup} = 12 V & R_{COIL} = 2.8 k Ω



10.3 System Examples

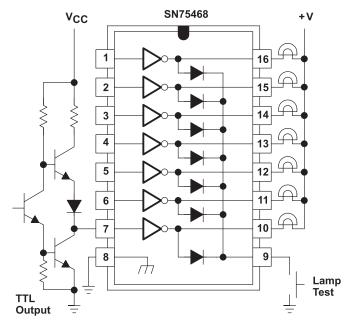


Figure 19. TTL to Load Schematic

Product Folder Links: SN75468 SN75469



System Examples (continued)

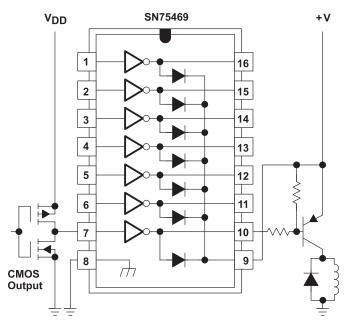


Figure 20. Buffer to Higher Current Loads Schematic

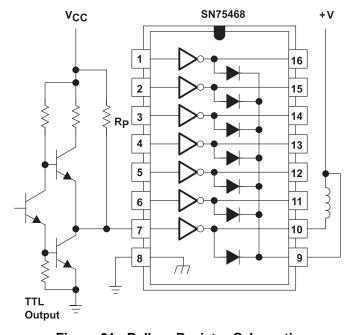


Figure 21. Pull-up Resistor Schematic



11 Power Supply Recommendations

This part does not need a power supply; however, the COM pin is typically tied to the system power supply. When this is the case, it is very important to make sure that the output voltage does not heavily exceed the COM pin voltage. This will heavily forward bias the fly-back diodes and cause a large current to flow into COM, potentially damaging the on-chip metal or over-heating the part.

12 Layout

12.1 Layout Guidelines

Thin traces can be used on the input due to the low current logic that is typically used to drive SN75468. Care must be taken to separate the input channels as much as possible, as to eliminate cross-talk. Thick traces are recommended for the output, in order to drive whatever high currents that may be needed. Wire thickness can be determined by the trace material's current density and desired drive current.

Since all of the channels currents return to a common emitter, it is best to size that trace width to be very wide. Some applications require up to 2.5 A.

12.2 Layout Example

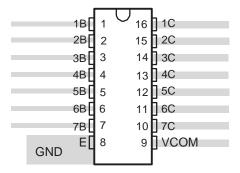


Figure 22. Package Layout

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13 Device and Documentation Support

13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN75468	Click here	Click here	Click here	Click here	Click here	
SN75469	Click here	Click here	Click here	Click here	Click here	

13.2 Trademarks

All trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN75468 SN75469

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
SN75468D	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75468
SN75468D.A	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75468
SN75468DE4	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75468
SN75468DR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75468
SN75468DR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75468
SN75468N	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75468N
SN75468N.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75468N
SN75468NE4	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75468N
SN75468NSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75468
SN75468NSR.A	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75468
SN75468NSRG4	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75468
SN75469D	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75469
SN75469D.A	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75469
SN75469DE4	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75469
SN75469DR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75469
SN75469DR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75469
SN75469N	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75469N
SN75469N.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75469N

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

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(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION

REEL DIMENSIONS Reel Diameter Reel Width (W1)

TAPE DIMENSIONS KO P1 BO W Cavity A0

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



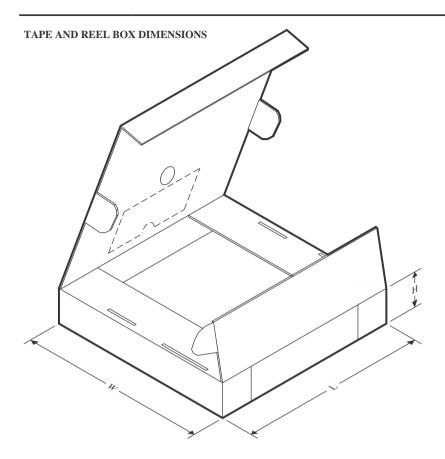
*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75468NSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
SN75469DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1





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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75468NSR	SOP	NS	16	2000	356.0	356.0	35.0
SN75469DR	SOIC	D	16	2500	340.5	336.1	32.0



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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN75468D	D	SOIC	16	40	507	8	3940	4.32
SN75468D.A	D	SOIC	16	40	507	8	3940	4.32
SN75468DE4	D	SOIC	16	40	507	8	3940	4.32
SN75468N	N	PDIP	16	25	506	13.97	11230	4.32
SN75468N	N	PDIP	16	25	506	13.97	11230	4.32
SN75468N.A	N	PDIP	16	25	506	13.97	11230	4.32
SN75468N.A	N	PDIP	16	25	506	13.97	11230	4.32
SN75468NE4	N	PDIP	16	25	506	13.97	11230	4.32
SN75468NE4	N	PDIP	16	25	506	13.97	11230	4.32
SN75469D	D	SOIC	16	40	507	8	3940	4.32
SN75469D.A	D	SOIC	16	40	507	8	3940	4.32
SN75469DE4	D	SOIC	16	40	507	8	3940	4.32
SN75469N	N	PDIP	16	25	506	13.97	11230	4.32
SN75469N.A	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



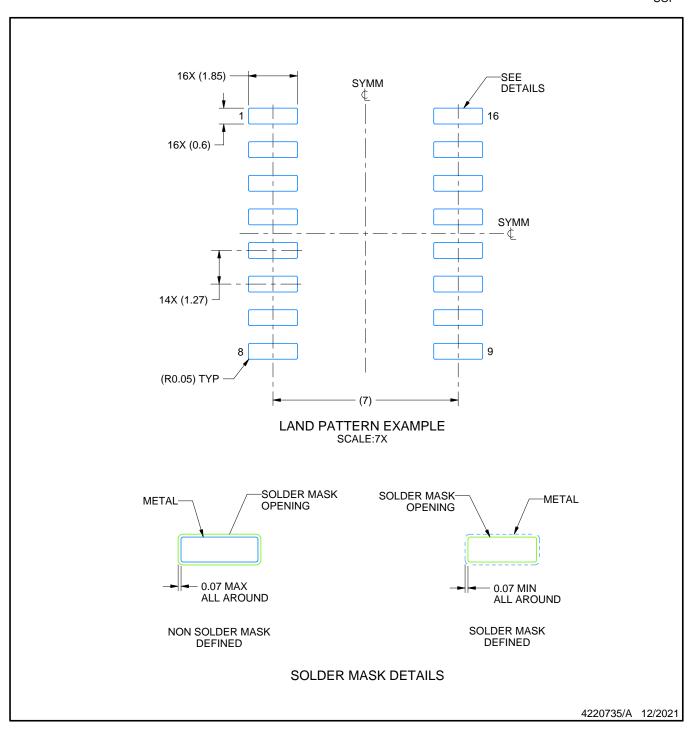
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF

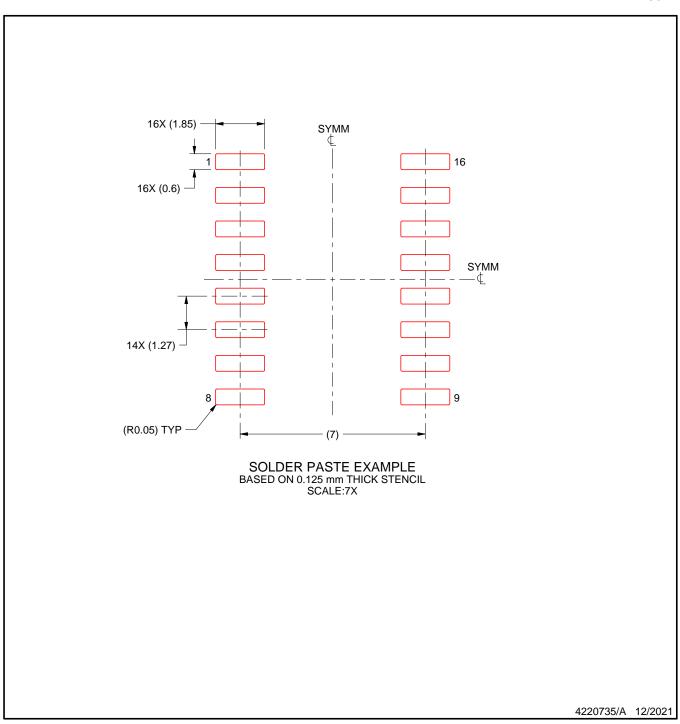


NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

SOF



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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